



1.Description

SS095N20LS, the N-channel Enhanced Power MOSFETs, is obtained by advanced double trench technology which reduce the conduction loss, improve switching performance and enhance the avalanche energy. This is suitable device for motor drivers and high speed switching applications.

KEY CHARACTERISTICS

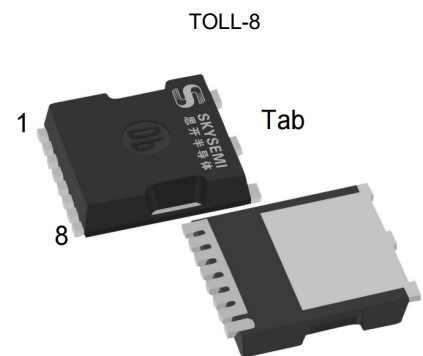
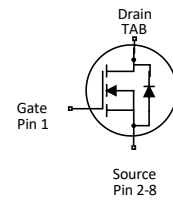
Parameter	Value	Unit
V _{DSS}	200	V
I _D	135	A
R _{DS(on)} .typ	9.0	mΩ

FEATURES

- Fast Switching
- Low On-Resistance ($R_{DS(on)} \leq 9.5\text{m}\Omega$)
- Low Gate Charge
- Low Reverse transfer capacitances
- High avalanche ruggedness
- RoHS product

APPLICATIONS

- Switching applications
- Motor drivers
- BMS
- Synchronous rectification



ORDERING INFORMATION

Ordering Codes	Package	Product Code	Packing	Quantity
SS095N20LS	TOLL-8L	SS095N20LS	Reel	2000